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November 2013

## FDH45N50F

# N-Channel UniFET<sup>TM</sup> FRFET<sup>®</sup> MOSFET 500 V, 45 A, 120 m $\Omega$

#### **Features**

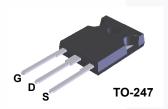
- $R_{DS(on)} = 105 \text{ m}\Omega \text{ (Typ.)} @ V_{GS} = 10 \text{ V, } I_D = 22.5 \text{ A}$
- Low Gate Charge (Typ. 105 nC)
- Low C<sub>rss</sub> (Typ. 62 pF)
- 100% Avalanche Tested
- · Improved dv/dt Capability

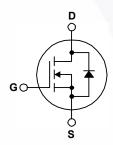
#### **Applications**

- · Lighting
- · Uninterruptible Power Supply
- · AC-DC Power Supply

#### Description

UniFET<sup>TM</sup> MOSFET is Fairchild Semiconductor's high voltage MOSFET family based on planar stripe and DMOS technology. This MOSFET is tailored to reduce on-state resistance, and to provide better switching performance and higher avalanche energy strength. The body diode's reverse recovery performance of UniFET FRFET® MOSFET has been enhanced by lifetime control. Its t<sub>rr</sub> is less than 100nsec and the reverse dv/dt immunity is 15V/ns while normal planar MOSFETs have over 200nsec and 4.5V/nsec respectively. Therefore, it can remove additional component and improve system reliability in certain applications in which the performance of MOSFET's body diode is significant. This device family is suitable for switching power converter applications such as power factor correction (PFC), flat panel display (FPD) TV power, ATX and electronic lamp ballasts





## Absolute Maximum Ratings T<sub>C</sub> = 25°C unless otherwise noted.

Symbol		FDH45N50F_F133	Unit	
$V_{DSS}$	Drain-Source Voltage		500	V
I <sub>D</sub>	Drain Current	- Continuous (T <sub>C</sub> = 25°C) - Continuous (T <sub>C</sub> = 100°C)	45 28.4	A A
I <sub>DM</sub>	Drain Current	- Pulsed (Note 1)	180	Α
V <sub>GSS</sub>	Gate-Source voltage	±30	V	
E <sub>AS</sub>	Single Pulsed Avalanche Energy (Note 2)		1868	mJ
I <sub>AR</sub>	Avalanche Current (Note 1)		45	Α
E <sub>AR</sub>	Repetitive Avalanche Energy (Note 1)		62.5	mJ
dv/dt	Peak Diode Recovery dv/dt (Note 3)		50	V/ns
P <sub>D</sub>	Power Dissipation	(T <sub>C</sub> = 25°C) - Derate Above 25°C	625 5	W W/°C
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temp	-55 to +150	°C	
T <sub>L</sub>	Maximum Lead Temperature	300	°C	

#### **Thermal Characteristics**

Symbol	Parameter	FDH45N50F_F133	Unit	
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case, Max.	0.2	°C/W	
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient, Max.	40	0/44	

## **Package Marking and Ordering Information**

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FDH45N50F_F133	FDH45N50F	TO-247	Tube	N/A	N/A	30 units

## **Electrical Characteristics** $T_C = 25^{\circ}C$ unless otherwise noted.

Symbol	Parameter	Conditions	Min.	Тур.	Max	Unit
Off Charac	Off Characteristics					
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$	500			V
ΔBV <sub>DSS</sub> / ΔT <sub>J</sub>	Breakdown Voltage Temperature Coefficient	I <sub>D</sub> = 250 μA, Referenced to 25°C		0.5		V/°C
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 500 V, V <sub>GS</sub> = 0 V V <sub>DS</sub> = 400 V, T <sub>C</sub> = 125°C			25 250	μA μA
I <sub>GSSF</sub>	Gate-Body Leakage Current, Forward	V <sub>GS</sub> = 30 V, V <sub>DS</sub> = 0 V			100	nA
I <sub>GSSR</sub>	Gate-Body Leakage Current, Reverse	V <sub>GS</sub> = -30 V, V <sub>DS</sub> = 0 V			-100	nA
On Charac	teristics					
V <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	3.0		5.0	V
R <sub>DS(on)</sub>	Static Drain-Source On-Resistance	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 22.5 A		0.105	0.12	Ω
9 <sub>FS</sub>	Forward Transconductance	V <sub>DS</sub> = 40 V, I <sub>D</sub> = 22.5 A	-	49.0		S
Dynamic C	Characteristics					
C <sub>iss</sub>	Input Capacitance	V <sub>DS</sub> = 25 V, V <sub>GS</sub> = 0 V,		5100	6630	pF
C <sub>oss</sub>	Output Capacitance	f = 1 MHz		790	1030	pF
C <sub>rss</sub>	Reverse Transfer Capacitance			62		pF
C <sub>oss</sub>	Output Capacitance	V <sub>DS</sub> = 400 V, V <sub>GS</sub> = 0 V, f = 1 MHz		161		pF
C <sub>oss(eff.)</sub>	Effective Output Capacitance	V <sub>DS</sub> = 0 V to 400 V, V <sub>GS</sub> = 0 V		342		pF
	Characteristics					
t <sub>d(on)</sub>	Turn-On Delay Time	V <sub>DD</sub> = 250 V, I <sub>D</sub> = 48 A,		140	290	ns
t <sub>r</sub>	Turn-On Rise Time	$V_{GS}$ = 10 V, $R_{G}$ = 25 $\Omega$		500	1010	ns
t <sub>d(off)</sub>	Turn-Off Delay Time		/	215	440	ns
t <sub>f</sub>	Turn-Off Fall Time	(Note 4)		245	500	ns
Qg	Total Gate Charge	V <sub>DS</sub> = 400 V, I <sub>D</sub> = 48 A,	/	105	137	nC
Q <sub>gs</sub>	Gate-Source Charge	V <sub>GS</sub> = 10 V		33		nC
Q <sub>gd</sub>	Gate-Drain Charge	(Note 4)		45		nC
Drain-Sour	rce Diode Characteristics and Maximur	n Ratings				
I <sub>S</sub>	Maximum Continuous Drain-Source Diode Forward Current				45	Α
I <sub>SM</sub>	Maximum Pulsed Drain-Source Diode Forward Current				180	Α
$V_{SD}$	Drain-Source Diode Forward Voltage	V <sub>GS</sub> = 0 V, I <sub>S</sub> = 45 A			1.4	V
t <sub>rr</sub>	Reverse Recovery Time	V <sub>GS</sub> = 0 V, I <sub>S</sub> = 45 A,		188	<b></b> [	ns
Q <sub>rr</sub>	Reverse Recovery Charge	dI <sub>F</sub> /dt =100 A/μs	-	0.64		μС

#### Notes

 $<sup>{\</sup>it 1. Repetitive\ rating: pulse-width\ limited\ by\ maximum\ junction\ temperature.}$ 

<sup>2.</sup> L = 1.46 mH, I  $_{AS}$  = 48 A, V  $_{DD}$  = 50 V, R  $_{G}$  = 25  $\Omega,$  starting T  $_{J}$  = 25  $^{\circ}C.$ 

<sup>3.</sup>  $I_{SD} \le$  45 A, di/dt  $\le$  200 A/µs,  $V_{DD} \le$  BV $_{DSS}$ , starting  $T_J$  = 25°C.

<sup>4.</sup> Essentially independent of operating temperature typical characteristics.

## **Typical Performance Characteristics**

Figure 1. On-Region Characteristics

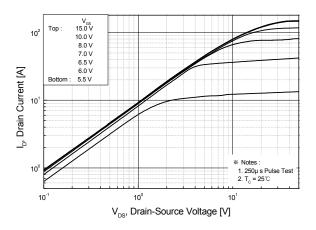


Figure 3. On-Resistance Variation vs.
Drain Current and Gate Voltage

Figure 2. Transfer Characteristics

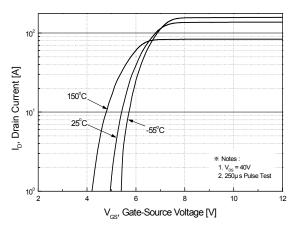


Figure 4. Body Diode Forward Voltage Variation vs. Source Current and Temperatue

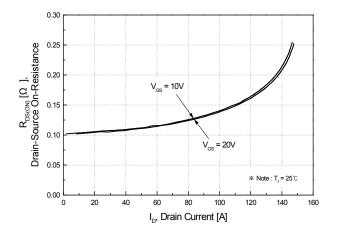
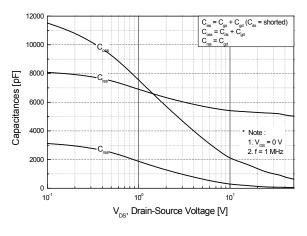


Figure 5. Capacitance Characteristics

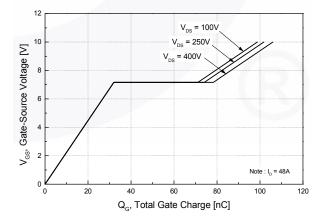


# Notes:
10°
10°
25°C

\*\* Notes:
1. V<sub>se</sub> = 0V
2. 250µ s Pulse Test

V<sub>sp</sub>, Source-Drain voltage [V]

Figure 6. Gate Charge Characteristics



#### **Typical Performance Characteristics** (Continued)

Figure 7. Breakdown Voltage Variation vs. Temperature

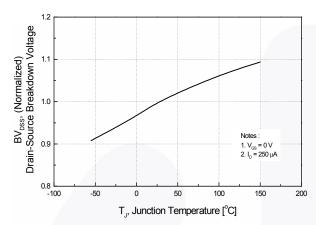


Figure 8. On-Resistance Variation vs. Temperature

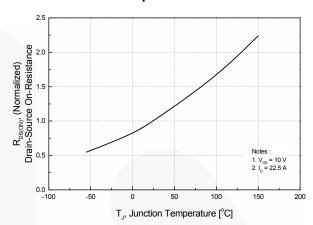


Figure 9. Maximum Safe Operating Area

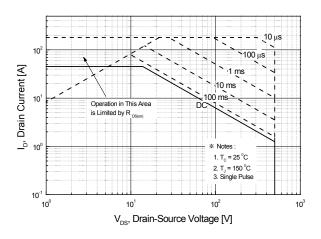


Figure 10. Maximum Drain Current vs. Case Temperature

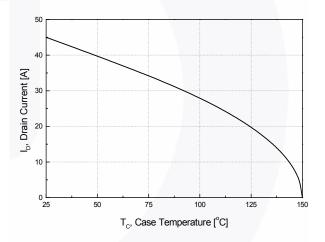


Figure 11. Typical Drain Current Slope vs. Gate Resistance

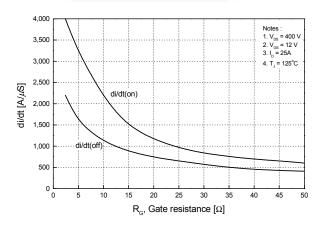
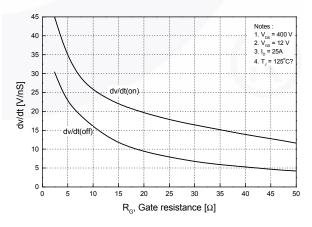


Figure 12. Typical Drain-Source Voltage Slope vs. Gate Resistance



## **Typical Performance Characteristics** (Continued)

Figure 13. Typical Switching Losses vs. Gate Resistance

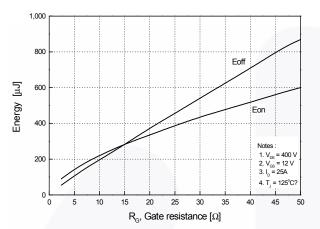


Figure 14. Unclamped Inductive Switching Capability

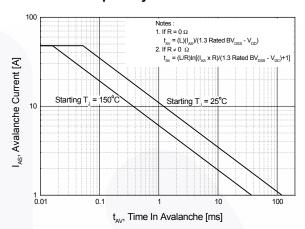
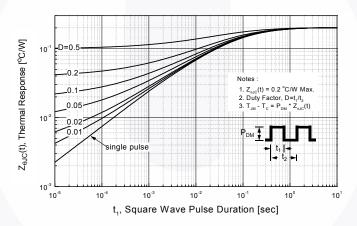


Figure 15. Transient Thermal Resistance Curve



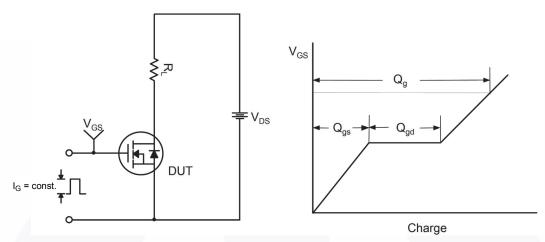


Figure 16. Gate Charge Test Circuit & Waveform

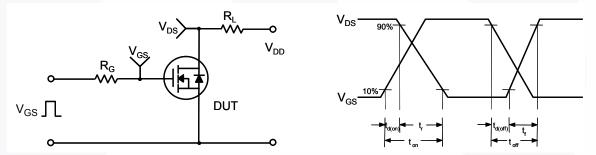


Figure 17. Resistive Switching Test Circuit & Waveforms

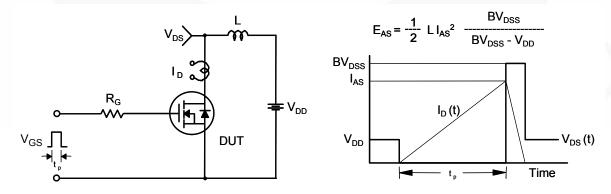


Figure 18. Unclamped Inductive Switching Test Circuit & Waveforms

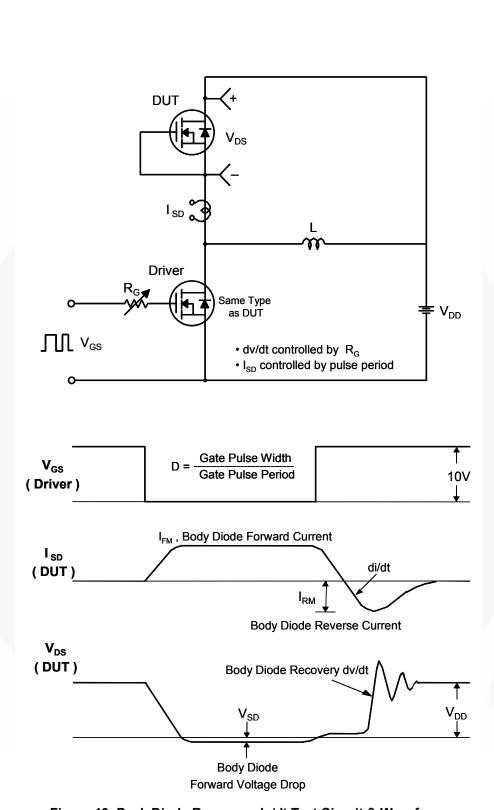
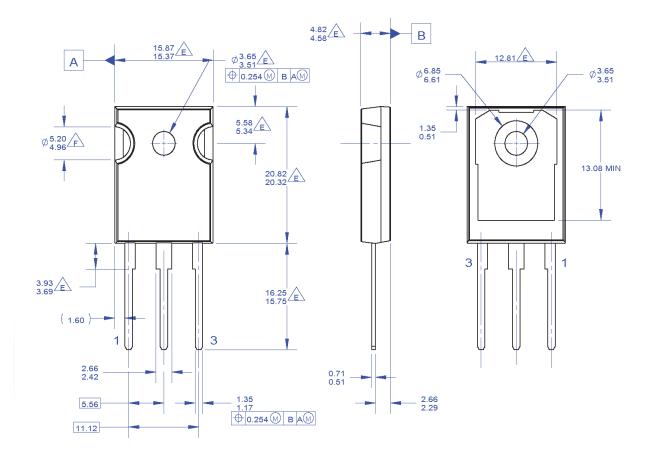


Figure 19. Peak Diode Recovery dv/dt Test Circuit & Waveforms

#### **Mechanical Dimensions**



NOTES: UNLESS OTHERWISE SPECIFIED

- A. PACKAGE REFERENCE: JEDEC TO-247,
- ISSUE E, VARIATION AB, DATED JUNE, 2004.

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G. DRAWING FILENAME: MKT-TO247A03\_REV03

#### Figure 20. TO-247, Molded, 3-Lead, Jedec Variation AB

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